ESP32-WROVER-B

Datasheet



About This Document

This document provides the specifications for the ESP32-WROVER-B modules with PCB antenna and IPEX antenna.

Revision History

For revision history of this document, please refer to the last page.

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Contents

1	Overview	1
2 2.1 2.2 2.3	Pin Description	3 3 4 5
3.1 3.2 3.3 3.4	External Flash and SRAM Crystal Oscillators	7 7 7 7 8
4	Peripherals and Sensors	9
5 5.1 5.2 5.3 5.4 5.5	Recommended Operating Conditions DC Characteristics (3.3V, 25°C) Wi-Fi Radio	10 10 10 10 11 11 11 12
6	Schematics	14
7	Peripheral Schematics	15
8	Physical Dimensions	17
9	Recommended PCB Land Pattern	18
10	OU.FL Connector Dimensions	19
11.	Learning Resources 1 Must-Read Documents 2 Must-Have Resources	20 20 20
Re	evision History	21

List of Tables

1	ESP32-WROVER-B Ordering Information	1
2	ESP32-WROVER-B Specifications	1
3	Pin Definitions	4
4	Strapping Pins	5
5	Absolute Maximum Ratings	10
6	Recommended Operating Conditions	10
7	DC Characteristics	10
8	Wi-Fi Radio Characteristics	11
9	Receiver Characteristics – BLE	11
10	Transmitter Characteristics – BLE	12

List of Figures

1	Pin Layout of ESP32-WROVER-B (Top View)	3
2	Reflow Profile	13
3	Schematics of ESP32-WROVER-B	14
4	Peripheral Schematics of ESP32-WROVER-B	15
5	Discharge Circuit for VDD33 Rail	15
6	Reset Circuit	16
7	Physical Dimensions of ESP32-WROVER-B (PCB/IPEX)	17
8	Recommended PCB Land Pattern of ESP32-WROVER-B	18
9	LLEL Connector Dimensions	10

1. Overview

ESP32-WROVER-B is a powerful, generic WiFi-BT-BLE MCU module that targets a wide variety of applications, ranging from low-power sensor networks to the most demanding tasks, such as voice encoding, music streaming and MP3 decoding.

This module is provided in two versions: one with a PCB antenna, the other with an IPEX antenna. ESP32-WROVER-B features a 4 MB external SPI flash and an additional 8 MB SPI Pseudo static RAM (PSRAM).

The ordering information on the two variants of ESP32-WROVER-B is listed as follows:

Table 1: ESP32-WROVER-B Ordering Information

Module	Chip embedded	Flash	PSRAM	Dimensions (mm)
ESP32-WROVER-B (PCB)	ESP32-D0WD	4 MB	8 MB	(18.00±0.10)x(31.40±0.10)x(3.30±0.10)
ESP32-WROVER-B (IPEX)	LOF02-DUVVD			(10.00 ± 0.10) X(31.40±0.10)X(3.30±0.10)

For diemsnions of the IPEX connector, please see Chapter 10. The information in this datasheet is applicable to both modules.

At the core of the module is the ESP32-D0WD chip*. The chip embedded is designed to be scalable and adaptive. There are two CPU cores that can be individually controlled, and the CPU clock frequency is adjustable from 80 MHz to 240 MHz. The user may also power off the CPU and make use of the low-power co-processor to constantly monitor the peripherals for changes or crossing of thresholds. ESP32 integrates a rich set of peripherals, ranging from capacitive touch sensors, Hall sensors, SD card interface, Ethernet, high-speed SPI, UART, I²S and I²C.

Note:

* For details on the part numbers of the ESP32 family of chips, please refer to the document ESP32 Datasheet.

The integration of Bluetooth, Bluetooth LE and Wi-Fi ensures that a wide range of applications can be targeted, and that the module is all-around: using Wi-Fi allows a large physical range and direct connection to the internet through a Wi-Fi router, while using Bluetooth allows the user to conveniently connect to the phone or broadcast low energy beacons for its detection. The sleep current of the ESP32 chip is less than 5 μ A, making it suitable for battery powered and wearable electronics applications. The module supports a data rate of up to 150 Mbps, and 20 dBm output power at the antenna to ensure the widest physical range. As such the module does offer industry-leading specifications and the best performance for electronic integration, range, power consumption, and connectivity.

The operating system chosen for ESP32 is freeRTOS with LwIP; TLS 1.2 with hardware acceleration is built in as well. Secure (encrypted) over the air (OTA) upgrade is also supported, so that developers can upgrade their products even after their release, at minimum cost and effort.

Table 2 provides the specifications of ESP32-WROVER-B.

Table 2: ESP32-WROVER-B Specifications

Categories	S Items Specifications		
	RF certification	FCC/CE-RED/IC/TELEC/KCC/SRRC/NCC	
Certification	Bluetooth certification	BQB	

Categories	Items	Specifications
	Green certification	RoHS, REACH
Test	Reliablity	HTOL/HTSL/uHAST/TCT/ESD
		802.11 b/g/n (802.11n up to 150 Mbps)
Wi-Fi	Protocols	A-MPDU and A-MSDU aggregation and 0.4 μs guard in-
V V I - I I		terval support
	Frequency range	2.4 GHz ~ 2.5 GHz
Bluetooth	Protocols	Bluetooth v4.2 BR/EDR and BLE specification
	Radio	NZIF receiver with -97 dBm sensitivity
		Class-1, class-2 and class-3 transmitter
		AFH
	Audio	CVSD and SBC
		SD card, UART, SPI, SDIO, I2C, LED PWM, Motor PWM,
	Module interfaces	I^2 S, IR, pulse counter, GPIO, capacitive touch sensor,
		ADC, DAC
	On-chip sensor	Hall sensor
	Integrated crystal	40 MHz crystal
Hardware	Operating voltage/Power supply	2.7 ~ 3.6V
	Minimum current delivered by	500 mA
	power supply	300 11/1
	Recommended operating tem-	 −40°C ~ 65°C
	perature range	10 0 00 0
	Package size	(18.00±0.10) mm x (31.40±0.10) mm x (3.30±0.10) mm

2. Pin Definitions

2.1 Pin Layout

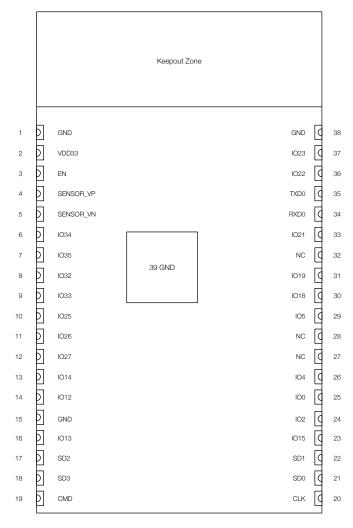


Figure 1: Pin Layout of ESP32-WROVER-B (Top View)

2.2 Pin Description

ESP32-WROVER-B has 38 pins. See pin definitions in Table 3.

Table 3: Pin Definitions

Name	No.	Туре	Function		
GND	1	Р	Ground		
3V3	2	Р	Power supply		
EN	3	I	Module-enable signal. Active high.		
SENSOR_VP	4	I	GPIO36, ADC1_CH0, RTC_GPIO0		
SENSOR_VN	5	1	GPIO39, ADC1_CH3, RTC_GPIO3		
IO34	6	I	GPIO34, ADC1_CH6, RTC_GPIO4		
IO35	7	I	GPIO35, ADC1_CH7, RTC_GPIO5		
IO32	8	I/O	GPIO32, XTAL_32K_P (32.768 kHz crystal oscillator input), ADC1_CH4, TOUCH9, RTC_GPIO9		
IO33	9	I/O	GPIO33, XTAL_32K_N (32.768 kHz crystal oscillator output), ADC1_CH5, TOUCH8, RTC_GPIO8		
1025	10	1/0	GPIO25, DAC_1, ADC2_CH8, RTC_GPIO6, EMAC_RXD0		
1026	11	1/0	GPIO26, DAC_2, ADC2_CH9, RTC_GPIO7, EMAC_RXD1		
1027	12	1/0	GPIO27, ADC2_CH7, TOUCH7, RTC_GPIO17, EMAC_RX_DV		
IO14	13	I/O	GPIO14, ADC2_CH6, TOUCH6, RTC_GPIO16, MTMS, HSPICLK, HS2_CLK, SD_CLK, EMAC_TXD2		
IO12	14	I/O	GPIO12, ADC2_CH5, TOUCH5, RTC_GPIO15, MTDI, HSPIQ, HS2_DATA2, SD_DATA2, EMAC_TXD3		
GND	15	Р	Ground		
		6 I/O	GPIO13, ADC2_CH4, TOUCH4, RTC_GPIO14, MTCK, HSPID,		
IO13	16		HS2_DATA3, SD_DATA3, EMAC_RX_ER		
SHD/SD2*	17	I/O	GPIO9, SD_DATA2, SPIHD, HS1_DATA2, U1RXD		
SWP/SD3*	18	I/O	GPIO10, SD_DATA3, SPIWP, HS1_DATA3, U1TXD		
SCS/CMD*	19	I/O	GPIO11, SD_CMD, SPICSO, HS1_CMD, U1RTS		
SCK/CLK*	20	I/O	GPIO6, SD_CLK, SPICLK, HS1_CLK, U1CTS		
SDO/SD0*	21	I/O	GPIO7, SD_DATA0, SPIQ, HS1_DATA0, U2RTS		
SDI/SD1*	22	I/O	GPIO8, SD_DATA1, SPID, HS1_DATA1, U2CTS		
IO15	23	I/O	GPIO15, ADC2_CH3, TOUCH3, MTDO, HSPICS0, RTC_GPIO13, HS2_CMD, SD_CMD, EMAC_RXD3		
IO2	24	I/O	GPIO2, ADC2_CH2, TOUCH2, RTC_GPIO12, HSPIWP, HS2_DATA0, SD_DATA0		
100	25	I/O	GPIO0, ADC2_CH1, TOUCH1, RTC_GPIO11, CLK_OUT1, EMAC_TX_CLK		
104	26	I/O	GPIO4, ADC2_CH0, TOUCH0, RTC_GPIO10, HSPIHD, HS2_DATA1, SD_DATA1, EMAC_TX_ER		
NC1	27	-	-		
NC2	28	-	-		
IO5	29	1/0	GPIO5, VSPICSO, HS1_DATA6, EMAC_RX_CLK		
IO18	30	I/O	GPIO18, VSPICLK, HS1_DATA7		
IO19	31	1/0	GPIO19, VSPIQ, U0CTS, EMAC_TXD0		

Name	No.	Туре	Function	
NC	32	-	-	
IO21	33	I/O	GPIO21, VSPIHD, EMAC_TX_EN	
RXD0	34	I/O	GPIO3, U0RXD, CLK_OUT2	
TXD0	35	I/O	SPIO1, U0TXD, CLK_OUT3, EMAC_RXD2	
IO22	36	I/O	GPIO22, VSPIWP, U0RTS, EMAC_TXD1	
IO23	37	I/O	GPIO23, VSPID, HS1_STROBE	
GND	38	Р	Ground	

Notice:

* Pins SCK/CLK, SDO/SD0, SDI/SD1, SHD/SD2, SWP/SD3 and SCS/CMD, namely, GPIO6 to GPIO11 are connected to the SPI flash integrated on the module and are not recommended for other uses.

2.3 Strapping Pins

ESP32 has five strapping pins, which can be seen in Chapter 6 Schematics:

- MTDI
- GPI00
- GPIO2
- MTDO
- GPIO5

Software can read the values of these five bits from register "GPIO_STRAPPING".

During the chip's system reset (power-on-reset, RTC watchdog reset and brownout reset), the latches of the strapping pins sample the voltage level as strapping bits of "0" or "1", and hold these bits until the chip is powered down or shut down. The strapping bits configure the device's boot mode, the operating voltage of VDD_SDIO and other initial system settings.

Each strapping pin is connected to its internal pull-up/pull-down during the chip reset. Consequently, if a strapping pin is unconnected or the connected external circuit is high-impedance, the internal weak pull-up/pull-down will determine the default input level of the strapping pins.

To change the strapping bit values, users can apply the external pull-down/pull-up resistances, or use the host MCU's GPIOs to control the voltage level of these pins when powering on ESP32.

After reset, the strapping pins work as normal-function pins.

Refer to Table 4 for a detailed boot-mode configuration by strapping pins.

Table 4: Strapping Pins

	Voltage of Internal LDO (VDD_SDIO)					
Pin Default 3.3V 1.8V						
MTDI	Pull-down	0	1			
	Booting Mode					
Pin	Default	SPI Boot	Download Boot			

GPIO0	Pull-up	-	1	0			
GPIO2	Pull-down	Don't	-care	0			
	Enabling/Disabling Debugging Log Print over U0TXD During Booting						
Pin	Default	UOTXD) Active	UOTXE) Silent		
MTDO	Pull-up	-	1	0			
			Timing of SDIO Slave				
Pin	Default	Falling-edge Input	Falling-edge Input	Rising-edge Input	Rising-edge Input		
ГШ		Falling-edge Output	Rising-edge Output	Falling-edge Output	Rising-edge Output		
MTDO	Pull-up	0 0		1	1		
GPIO5 Pull-up 0 1		1	0	1			

Note:

- Firmware can configure register bits to change the settings of "Voltage of Internal LDO (VDD_SDIO)" and "Timing of SDIO Slave" after booting.
- Internal pull-up resistor (R9) for MTDI is not populated in the module, as the flash and SRAM in ESP32-WROVER-B only support a power voltage of 3.3V (output by VDD_SDIO).

3. Functional Description

This chapter describes the modules and functions integrated in ESP32-WROVER-B.

3.1 CPU and Internal Memory

ESP32-D0WD contains two low-power Xtensa® 32-bit LX6 microprocessors. The internal memory includes:

- 448 KB of ROM for booting and core functions.
- 520 KB of on-chip SRAM for data and instructions.
- 8 KB of SRAM in RTC, which is called RTC FAST Memory and can be used for data storage; it is accessed by the main CPU during RTC Boot from the Deep-sleep mode.
- 8 KB of SRAM in RTC, which is called RTC SLOW Memory and can be accessed by the co-processor during the Deep-sleep mode.
- 1 Kbit of eFuse: 256 bits are used for the system (MAC address and chip configuration) and the remaining 768 bits are reserved for customer applications, including flash-encryption and chip-ID.

3.2 External Flash and SRAM

ESP32 supports multiple external QSPI flash and SRAM chips. More details can be found in Chapter SPI in the <u>ESP32 Technical Reference Manual</u>. ESP32 also supports hardware encryption/decryption based on AES to protect developers' programs and data in flash.

ESP32 can access the external QSPI flash and SRAM through high-speed caches.

- The external flash can be mapped into CPU instruction memory space and read-only memory space simultaneously.
 - When external flash is mapped into CPU instruction memory space, up to 11 MB+248 KB can be mapped at a time. Note that if more than 3 MB+248 KB are mapped, cache performance will be reduced due to speculative reads by the CPU.
 - When external flash is mapped into read-only data memory space, up to 4 MB can be mapped at a time. 8-bit, 16-bit and 32-bit reads are supported.
- External SRAM can be mapped into CPU data memory space. Up to 4 MB can be mapped at a time. 8-bit, 16-bit and 32-bit reads and writes are supported.

ESP32-WROVER-B integrates a 4 MB SPI flash and an 8 MB PSRAM for more memory space.

3.3 Crystal Oscillators

The module uses a 40-MHz crystal oscillator.

3.4 RTC and Low-Power Management

With the use of advanced power-management technologies, ESP32 can switch between different power modes.

For details on ESP32's power consumption in different power modes, please refer to section "RTC and Low-Power Management" in *ESP32 Datasheet*.

4. Peripherals and Sensors

Please refer to Section Peripherals and Sensors in *ESP32 Datasheet*.

Note:

External connections can be made to any GPIO except for GPIOs in the range 6-11, 16, or 17. GPIOs 6-11 are connected to the module's integrated SPI flash and PSRAM. GPIOs 16 and 17 are connected to the module's integrated PSRAM. For details, please see Section 6 Schematics.

5. Electrical Characteristics

5.1 Absolute Maximum Ratings

Stresses beyond the absolute maximum ratings listed in the table below may cause permanent damage to the device. These are stress ratings only, and do not refer to the functional operation of the device.

Table 5: Absolute Maximum Ratings

Symbol	Parameter	Min	Max	Unit
VDD33	Power supply voltage	-0.3	3.6	V
T_{store}	Storage temperature	-40	150	°C

5.2 Recommended Operating Conditions

Table 6: Recommended Operating Conditions

Symbol	Parameter	Min	Typical	Max	Unit
VDD33	Power supply voltage	2.7	3.3	3.6	V
I_{VDD}	Current delivered by external power supply	0.5	-	-	А
Т	Operating temperature	-40	-	65	°C

5.3 DC Characteristics (3.3V, 25°C)

Table 7: DC Characteristics

Symbol	Parameter	Min	Тур	Max	Unit
C_{IN}	Pin capacitance	-	2	-	pF
V_{IH}	High-level input voltage	$0.75 \times VDD^1$	-	VDD + 0.3	V
V_{IL}	Low-level input voltage	-0.3	-	0.25 × VDD	V
$ \cdot _{IH}$	High-level input current	-	-	50	nA
I_{IL}	Low-level input current	-	-	50	nA
V_{OH}	High-level output voltage	0.8 × VDD	-	-	V
V_{OL}	Low-level output voltage	-	-	0.1 × VDD	V
	High-level source current (VDD = 3.3V, V_{OH} =		40	-	mA
$ I_{OH} $	2.64V, PAD_DRIVER = 3)	_	40		
1.	Low-level sink current (VDD = 3.3V, V_{OL} =		28		mA
$ I_{OL} $	0.495V, PAD_DRIVER = 3)	_	20	_	IIIA
R_{PU}	Pull-up resistor	-	45	-	kΩ
R_{PD}	Pull-down resistor	-	45	-	kΩ
V_{IL_nRST}	Low-level input voltage of EN to reset the mod-	_		0.6	V
	ule	_	-	0.0	v

^{1.} VDD is the I/O voltage for a particular power domain of pins. More details can be found in Appendix IO_MUX of ESP32 Datasheet.

5.4 Wi-Fi Radio

Table 8: Wi-Fi Radio Characteristics

Parameter	Min	Typical	Max	Unit
Input frequency	2412	-	2484	MHz
Output impedance*	-	*	-	Ω
	TX power			
Output power of PA for 72.2 Mbps	12	13	14	dBm
Output power of PA for 11b mode	17.5	18.5	20	dBm
	Sensitivity			
DSSS, 1 Mbps	-	-98	-	dBm
CCK, 11 Mbps	-	-89	-	dBm
6 Mbps (1/2 BPSK)	-	-92	-	dBm
54 Mbps (3/4 64-QAM)	-	-74	-	dBm
HT20, MCS0	-	- 91	-	dBm
HT20, MCS7	-	-71	-	dBm
HT40, MCS0	-	-89	-	dBm
HT40, MCS7	-	-69	-	dBm
Adjacent channel rejection				
OFDM, 6 Mbps	-	31	-	dB
OFDM, 54 Mbps	-	14	-	dB
HT20, MCS0	-	31	-	dB
HT20, MCS7	-	13	-	dB

^{*}For the modules that use IPEX antennas, the output impedance is 50Ω . For other modules without IPEX antennas, users do not need to concern about the output impedance.

5.5 BLE Radio

5.5.1 Receiver

Table 9: Receiver Characteristics - BLE

Parameter	Conditions	Min	Тур	Max	Unit
Sensitivity @30.8% PER	-	-	- 97	-	dBm
Maximum received signal @30.8% PER	-	0	-	-	dBm
Co-channel C/I	-	-	+10	-	dB
	F = F0 + 1 MHz	-	- 5	-	dB
	F = F0 - 1 MHz	-	- 5	-	dB
Adjacent channel selectivity C/I	F = F0 + 2 MHz	-	-25	-	dB
Adjacent charmer selectivity 0/1	F = F0 - 2 MHz	-	-35	-	dB
	F = F0 + 3 MHz	-	-25	-	dB
	F = F0 - 3 MHz	-	-45	-	dB

Parameter	Conditions	Min	Тур	Max	Unit
	30 MHz ~ 2000 MHz	-10	-	-	dBm
Out-of-band blocking performance	2000 MHz ~ 2400 MHz	-27	-	-	dBm
Out-or-band blocking penormance	2500 MHz ~ 3000 MHz	-27	-	-	dBm
	3000 MHz ~ 12.5 GHz	-10	-	-	dBm
Intermodulation	-	-36	-	-	dBm

5.5.2 Transmitter

Table 10: Transmitter Characteristics - BLE

Parameter	Conditions	Min	Тур	Max	Unit
RF transmit power	-	-	0	-	dBm
Gain control step	-	-	3	-	dBm
RF power control range	-	-12	-	+12	dBm
	$F = F0 \pm 2 MHz$	-	-52	-	dBm
Adjacent channel transmit power	$F = F0 \pm 3 MHz$	-	-58	-	dBm
	$F = F0 \pm > 3 MHz$	-	-60	-	dBm
$\Delta f1_{avg}$	-	-	-	265	kHz
$\Delta f2$ max	-	247	-	-	kHz
$\Delta f 2_{\text{avg}}/\Delta f 1_{\text{avg}}$	-	-	-0.92	-	-
ICFT	-	-	-10	-	kHz
Drift rate	-	-	0.7	-	kHz/50 μs
Drift	-	-	2	-	kHz

5.6 Reflow Profile

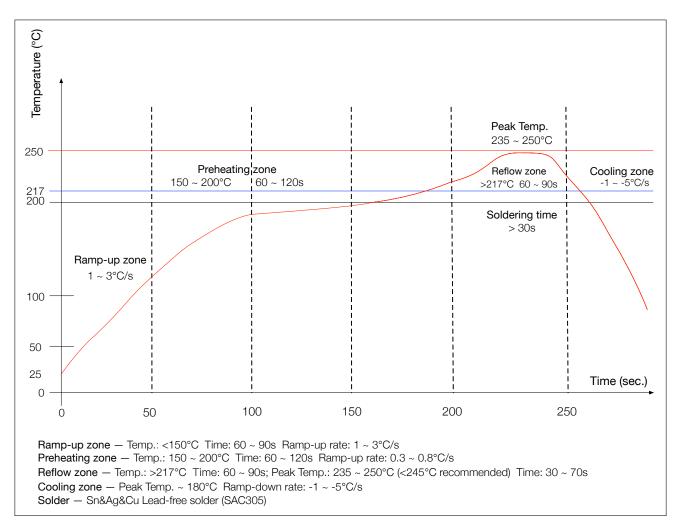


Figure 2: Reflow Profile

6. Schematics

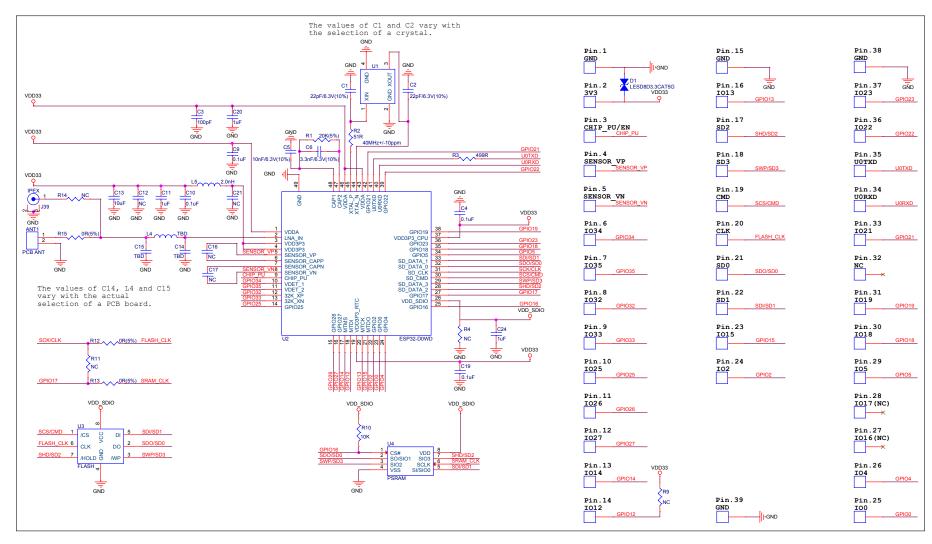


Figure 3: Schematics of ESP32-WROVER-B

7. Peripheral Schematics

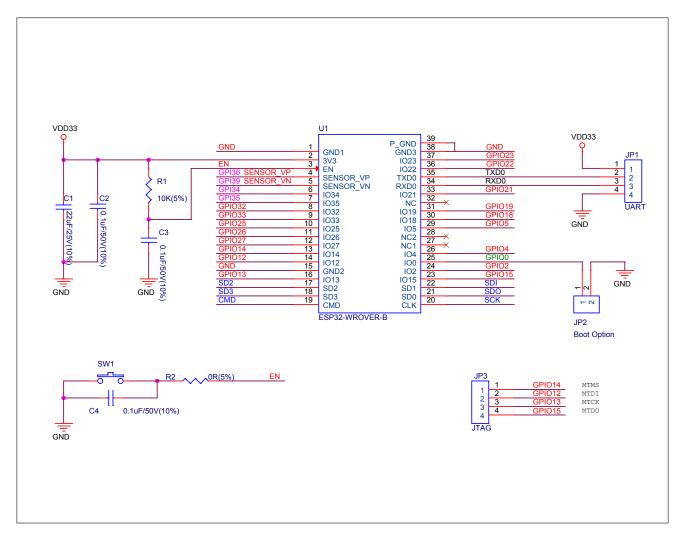


Figure 4: Peripheral Schematics of ESP32-WROVER-B

Note:

Soldering Pad 39 to the Ground of the base board is not necessary for a satisfactory thermal performance. If users do want to solder it, they need to ensure that the correct quantity of soldering paste is applied.

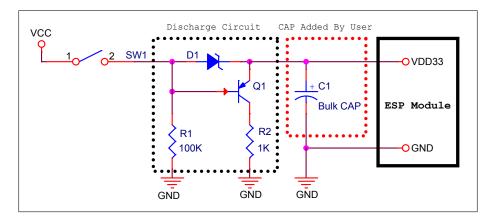


Figure 5: Discharge Circuit for VDD33 Rail

Note:

The discharge circuit can be applied in scenarios where ESP32 is powered on and off repeatedly by switching the power rails, and there is a large capacitor on the VDD33 rail. For details, please refer to Section **Power Scheme** in *ESP32 Datasheet*.

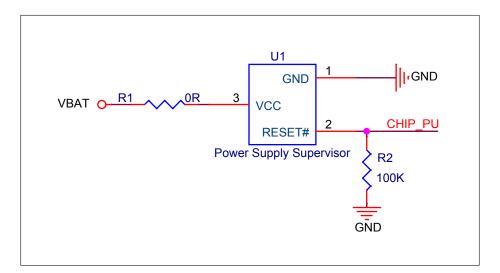
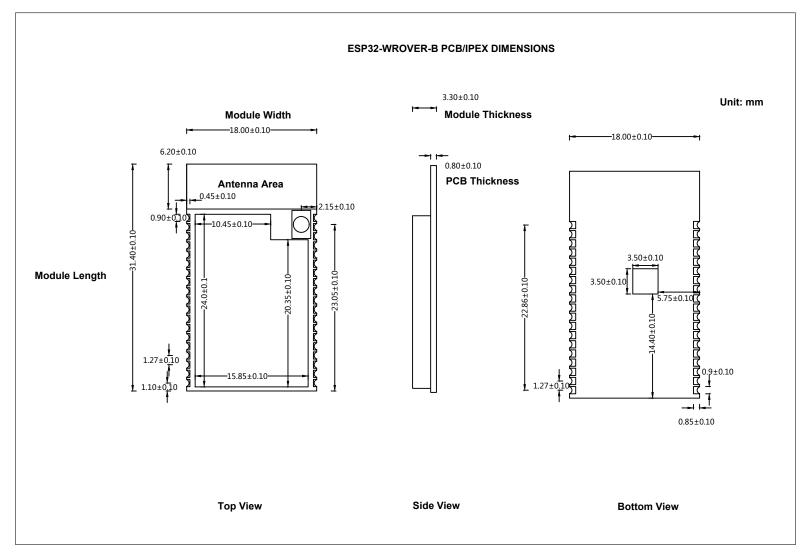


Figure 6: Reset Circuit

Note:

When battery is used as the power supply for ESP32 series of chips and modules, a supply voltage supervisor is recommended to avoid boot failure due to low voltage. Users are recommended to pull CHIP_PU low if the power supply for ESP32 is below 2.3V.

8. Physical Dimensions



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Physical Dimensions

Figure 7: Physical Dimensions of ESP32-WROVER-B (PCB/IPEX)

9. Recommended PCB Land Pattern

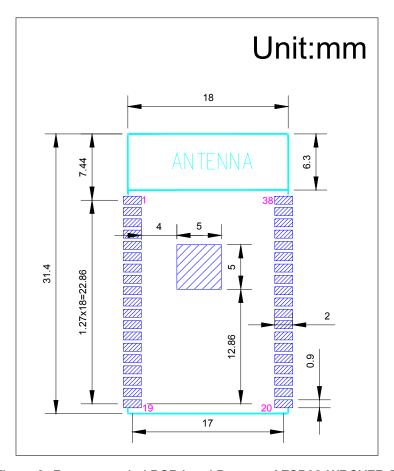


Figure 8: Recommended PCB Land Pattern of ESP32-WROVER-B

10. U.FL Connector Dimensions

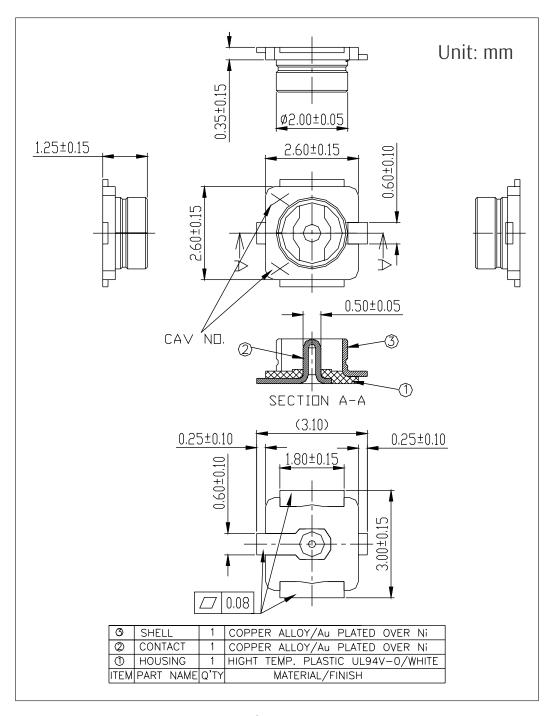


Figure 9: U.FL Connector Dimensions

11. Learning Resources

11.1 Must-Read Documents

The following link provides documents related to ESP32.

• ESP32 Datasheet

This document provides an introduction to the specifications of the ESP32 hardware, including overview, pin definitions, functional description, peripheral interface, electrical characteristics, etc.

• ESP-IDF Programming Guide

It hosts extensive documentation for ESP-IDF ranging from hardware guides to API reference.

• ESP32 Technical Reference Manual

The manual provides detailed information on how to use the ESP32 memory and peripherals.

• ESP32 Hardware Resources

The zip files include the schematics, PCB layout, Gerber and BOM list of ESP32 modules and development boards.

• ESP32 Hardware Design Guidelines

The guidelines outline recommended design practices when developing standalone or add-on systems based on the ESP32 series of products, including the ESP32 chip, the ESP32 modules and development boards.

• ESP32 AT Instruction Set and Examples

This document introduces the ESP32 AT commands, explains how to use them, and provides examples of several common AT commands.

• Espressif Products Ordering Information

11.2 Must-Have Resources

Here are the ESP32-related must-have resources.

• ESP32 BBS

This is an Engineer-to-Engineer (E2E) Community for ESP32 where you can post questions, share knowledge, explore ideas, and help solve problems with fellow engineers.

• ESP32 GitHub

ESP32 development projects are freely distributed under Espressif's MIT license on GitHub. It is established to help developers get started with ESP32 and foster innovation and the growth of general knowledge about the hardware and software surrounding ESP32 devices.

ESP32 Tools

This is a webpage where users can download ESP32 Flash Download Tools and the zip file "ESP32 Certification and Test".

• ESP-IDF

This webpage links users to the official IoT development framework for ESP32.

• ESP32 Resources

This webpage provides the links to all available ESP32 documents, SDK and tools.

Revision History

Date	Version	Release notes
2018.07	V1.0	Official release:
		Added certifications and reliability test items the module has passed in Table
		2: ESP32-WROVER-B Specifications;
		Updated the dimensions of the module;
		• Changed the module's recommended operating temperature from -40°C ~
		85°C to -40°C ~ 65°C;
		Updated table 8: Wi-Fi Radio.
2018.06	V0.1	Preliminary release.